

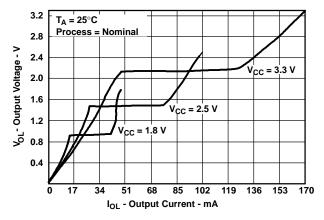
FEATURES

- Member of the Texas Instruments Widebus™ Family
- DOC[™] (Dynamic Output Control) Circuit Dynamically Changes Output Impedance, Resulting in Noise Reduction Without Speed Degradation
- Less Than 2-ns Maximum Propagation Delay at 2.5-V and 3.3-V V_{CC}
- Dynamic Drive Capability Is Equivalent to Standard Outputs With I $_{\rm OH}$ and I $_{\rm OL}$ of \pm 24 mA at 2.5-V V $_{\rm CC}$

- Overvoltage-Tolerant Inputs/Outputs Allow Mixed-Voltage-Mode Data Communications
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)

DESCRIPTION/ORDERING INFORMATION

A Dynamic Output Control (DOC) circuit is implemented, which, during the transition, initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figure 1 shows typical V_{OL} vs I_{OL} and V_{OH} vs I_{OH} curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DOC circuit provides a maximum dynamic drive that is equivalent to a high-drive standard-output device. For more information, refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number SCEA006, and *Dynamic Output Control (DOC*TM) *Circuitry Technology and Applications*, literature number SCEA009.



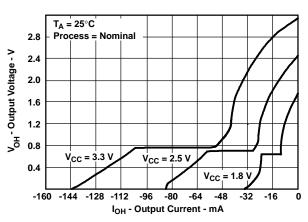


Figure 1. Output Voltage vs Output Current

ORDERING INFORMATION

T _A	PACK	AGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
	TSSOP - DGG	Tape and reel	SN74AVC16244DGGR	AVC16244		
–40°C to 85°C	TVSOP - DGV	Tape and reel	SN74AVC16244DGVR	CVA244		
-40 C to 65 C	VFBGA – GQL	Topo and roal	SN74AVC16244GQLR	- CVA244		
	VFBGA – ZQL (Pb-free)	Tape and reel	SN74AVC16244ZQLR	UVA244		

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

This 16-bit buffer/driver is operational at 1.2-V to 3.6-V V_{CC} , but is designed specifically for 1.65-V to 3.6-V V_{CC} operation.

The SN74AVC16244 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. It provides true outputs and symmetrical active-low output-enable (\overline{OE}) inputs.

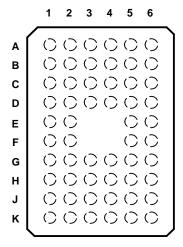
This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

DGG OR DGV PACKAGE (TOP VIEW)								
		`	_		1			
1 OE	d	1	J	48	2 <u>OE</u>			
1Y1		2		47] 1A1			
1Y2		3		46] 1A2			
GND	Ц	4		45	GND			
1Y3		5		44] 1A3			
1Y4		6		43] 1A4			
V_{CC}		7		42] v _{cc}			
2Y1	Ц	8		41] 2A1			
2Y2		9		40] 2A2			
GND	П	10		39	GND			
2Y3	Ц	11		38] 2A3			
2Y4	Ц	12		37] 2A4			
3Y1	Ц	13		36] 3A1			
3Y2		14		35] 3A2			
GND	П	15		34	GND			
3Y3	Ц	16		33] 3A3			
3Y4		17		32] 3A4			
V_{CC}	П	18		31] v _{cc}			
4Y1		19		30] 4A1			
4Y2	П	20		29] 4A2			
GND		21		28	GND			
4Y3	Ц	22		27] 4A3			
4Y4		23		26] 4A4			
4 OE	9	24		25	3 <u>OE</u>			



GQL OR ZQL PACKAGE (TOP VIEW)



TERMINAL ASSIGNMENTS(1)

	1	2	3	4	5	6
Α	1 OE	NC	NC	NC	NC	2 OE
В	1Y2	1Y1	GND	GND	1A1	1A2
С	1Y4	1Y3	V _{CC}	V _{CC}	1A3	1A4
D	2Y2	2Y1	GND	GND	2A1	2A2
E	2Y4	2Y3			2A3	2A4
F	3Y1	3Y2			3A2	3A1
G	3Y3	3Y4	GND	GND	3A4	3A3
Н	4Y1	4Y2	V _{CC}	V _{CC}	4A2	4A1
J	4Y3	4Y4	GND	GND	4A4	4A3
K	4 OE	NC	NC	NC	NC	3 OE

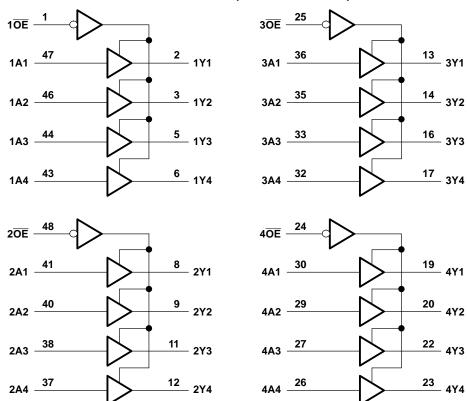
(1) NC - No internal connection

FUNCTION TABLE (EACH 4-BIT BUFFER)

INP	JTS	OUTPUT
ŌĒ	Α	Y
L	L	L
L	Н	Н
Н	Χ	Z



LOGIC DIAGRAM (POSITIVE LOGIC)

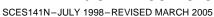


Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage range ⁽²⁾		-0.5	4.6	V
Vo	Voltage range applied to any output in	the high-impedance or power-off state (2)	-0.5	4.6	V
Vo	Voltage range applied to any output in	-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through each V _{CC} of	or GND		±100	mA
		DGG package		70	
θ_{JA}	Package thermal impedance (4)	DGV package		58	°C/W
		GQL/ZQL package		42	
T _{stg}	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.
- (4) The package thermal impedance is calculated in accordance with JESD 51.





Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V	Cumply voltage	Operating	1.4	3.6	V
V_{CC}	Supply voltage	Data retention only	1.2		V
		V _{CC} = 1.2 V	V _{CC}		
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	$0.65 \times V_{CC}$		
V_{IH}	High-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	$0.65 \times V_{CC}$		V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		
		V _{CC} = 3 V to 3.6 V	2		
		V _{CC} = 1.2 V		GND	
		V _{CC} = 1.4 V to 1.6 V		$0.35 \times V_{CC}$	
V_{IL}	Low-level input voltage	V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	V
		V _{CC} = 2.3 V to 2.7 V		0.7	
		V _{CC} = 3 V to 3.6 V		0.8	
VI	Input voltage		0	3.6	V
V	Output valtage	Active state	0	V_{CC}	V
Vo	Output voltage	3-state	0	3.6	V
		V _{CC} = 1.4 V to 1.6 V		-2	
	Static high level cutout current(2)	V _{CC} = 1.65 V to 1.95 V		-4	A
I _{OHS}	Static high-level output current ⁽²⁾	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-8	mA
		V _{CC} = 3 V to 3.6 V			
		V _{CC} = 1.4 V to 1.6 V		2	
	Static law layer output ourrent(2)	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	4		A
l _{OLS}	Static low-level output current ⁽²⁾	V _{CC} = 2.3 V to 2.7 V		mA	
		V _{CC} = 3 V to 3.6 V		12	
Δt/Δν	Input transition rise or fall rate	V _{CC} = 1.4 V to 3.6 V		5	ns/V
T _A	Operating free-air temperature		-40	85	°C

All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004. Dynamic drive capability is equivalent to standard outputs with I_{OH} and I_{OL} of ± 24 mA at 2.5-V V_{CC} . See Figure 1 for V_{OL} vs I_{OL} and V_{OH} vs I_{OH} characteristics. Refer to the TI application reports, AVC Logic Family Technology and Applications, literature number SCEA006, and Dynamic Output Control (DOCTM) Circuitry Technology and Applications, literature number SCEA009.

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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

F	PARAMETER	TEST CONDITIONS	V _{cc}	MIN TYP(1) MAX	UNIT	
		$I_{OHS} = -100 \mu A$	1.4 V to 3.6 V	V _{CC} -0.2		
		$I_{OHS} = -2 \text{ mA}, \qquad V_{IH} = 0.91 \text{ V}$	1.4 V	1.05		
V_{OH}		$I_{OHS} = -4 \text{ mA}, \qquad V_{IH} = 1.07 \text{ V}$	1.65 V	1.2	V	
		$I_{OHS} = -8 \text{ mA}, \qquad V_{IH} = 1.7 \text{ V}$	2.3 V	1.75		
		$I_{OHS} = -12 \text{ mA}, \qquad V_{IH} = 2 \text{ V}$	3 V	2.3		
		$I_{OLS} = 100 \mu A$	1.4 V to 3.6 V	0.2		
		$I_{OLS} = 2 \text{ mA}, \qquad V_{IL} = 0.49 \text{ V}$	1.4 V	0.4		
V_{OL}		$I_{OLS} = 4 \text{ mA}, \qquad \qquad V_{IL} = 0.57 \text{ V}$	1.65 V	0.45	V	
		$I_{OLS} = 8 \text{ mA}, \qquad \qquad V_{IL} = 0.7 \text{ V}$	2.3 V	0.55		
		$I_{OLS} = 12 \text{ mA}, \qquad V_{IL} = 0.8 \text{ V}$	3 V	0.7		
I_{\parallel}		$V_I = V_{CC}$ or GND	3.6 V	±2.5	μΑ	
I _{off}		V_I or $V_O = 3.6 \text{ V}$	0	±10	μΑ	
l _{OZ}		$V_O = V_{CC}$ or GND	3.6 V	±10	μΑ	
I _{CC}		$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V	40	μΑ	
	Control inputs	V – V or CND	2.5 V	3.5		
0	Control inputs	$V_I = V_{CC}$ or GND	3.3 V	3.5	~F	
Ci	Data inputa	V V or CND	2.5 V	6	pF	
	Data inputs	$V_I = V_{CC}$ or GND	3.3 V	6		
C	Outputo	V = V or CND	2.5 V	6.5	nE.	
C _o	Outputs	$V_O = V_{CC}$ or GND	3.3 V	6.5	pF	

⁽¹⁾ Typical values are measured at $T_A = 25$ °C.

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.2 V	V _{CC} = ± 0.1		V _{CC} = ± 0.1		V _{CC} = ± 0.2		V _{CC} = 1 ± 0.3		UNIT
	(INPUT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	Α	Y	3.1	0.6	3.3	0.7	2.9	0.6	1.9	0.5	1.7	ns
t _{en}	ŌĒ	Υ	7.6	1.4	8	1.3	6.8	0.9	4	0.7	3.5	ns
t _{dis}	ŌĒ	Υ	7.2	1.7	7.3	1.6	6.2	1	4.3	1	3.5	ns

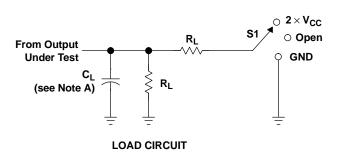
Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST (CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	UNIT	
0	Power dissipation	Outputs enabled	0 0	f 10 MHz	23	27	33	۲.
C _{pd} capacitance		Outputs disabled	$C_L = 0,$	f = 10 MHz	0.1	0.1	0.1	pF

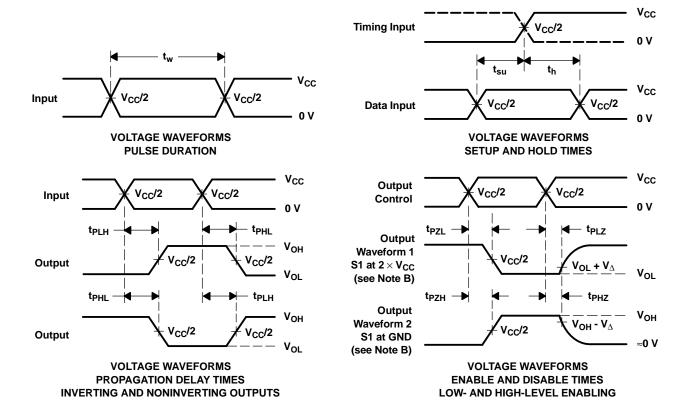


PARAMETER MEASUREMENT INFORMATION



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	$2 \times V_{CC}$
t _{PHZ} /t _{PZH}	GND

V _{CC}	CL	RL	${f V}_{\Delta}$
1.2 V	15 pF	2 k Ω	0.1 V
1.5 V \pm 0.1 V	15 pF	2 k Ω	0.1 V
1.8 V \pm 0.15 V	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	30 pF	500 Ω	0.15 V
3.3 V \pm 0.3 V	30 pF	500 Ω	0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{Ω} = 50 Ω , slew rate \geq 1 V/ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd}.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms



PACKAGE OPTION ADDENDUM

24-Aug-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74AVC16244DGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AVC16244	Samples
SN74AVC16244DGVR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CVA244	Samples
SN74AVC16244ZQLR	ACTIVE	BGA MICROSTAR JUNIOR	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	CVA244	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- ⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

24-Aug-2018

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





_	_	
		3
	B0	Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVC16244DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
SN74AVC16244DGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1
SN74AVC16244ZQLR	BGA MI CROSTA R JUNI OR	ZQL	56	1000	330.0	16.4	4.8	7.3	1.5	8.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVC16244DGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74AVC16244DGVR	TVSOP	DGV	48	2000	367.0	367.0	38.0
SN74AVC16244ZQLR	BGA MICROSTAR JUNIOR	ZQL	56	1000	350.0	350.0	43.0

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

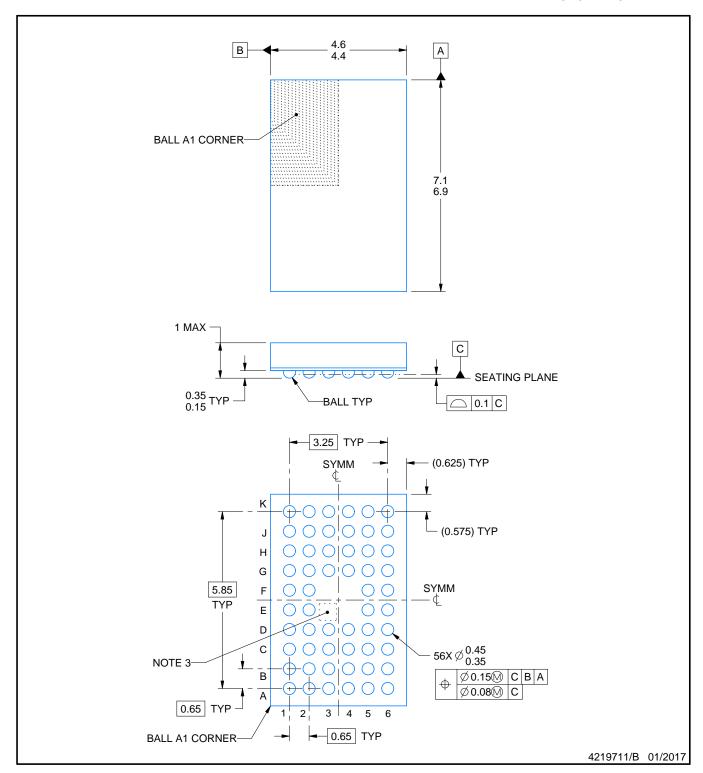
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153



PLASTIC BALL GRID ARRAY



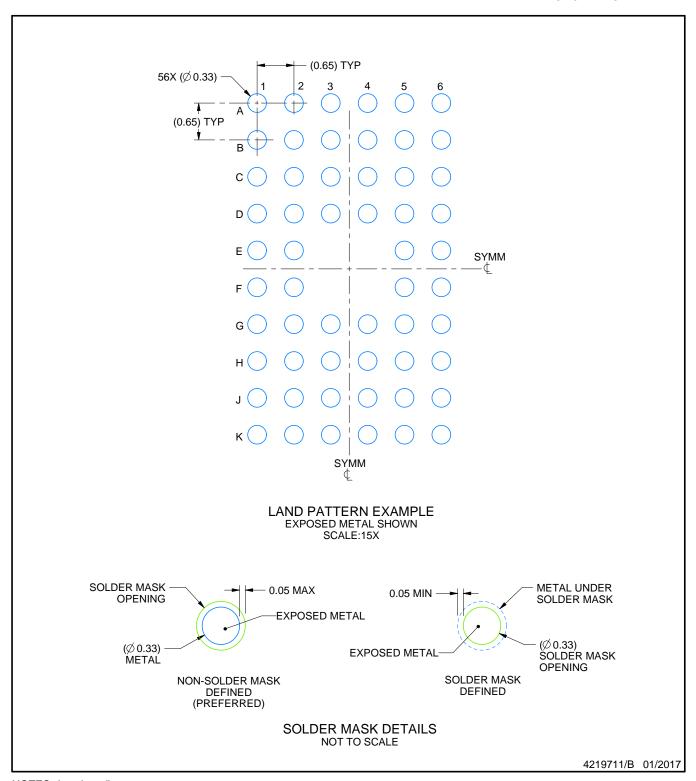
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. No metal in this area, indicates orientation.



PLASTIC BALL GRID ARRAY

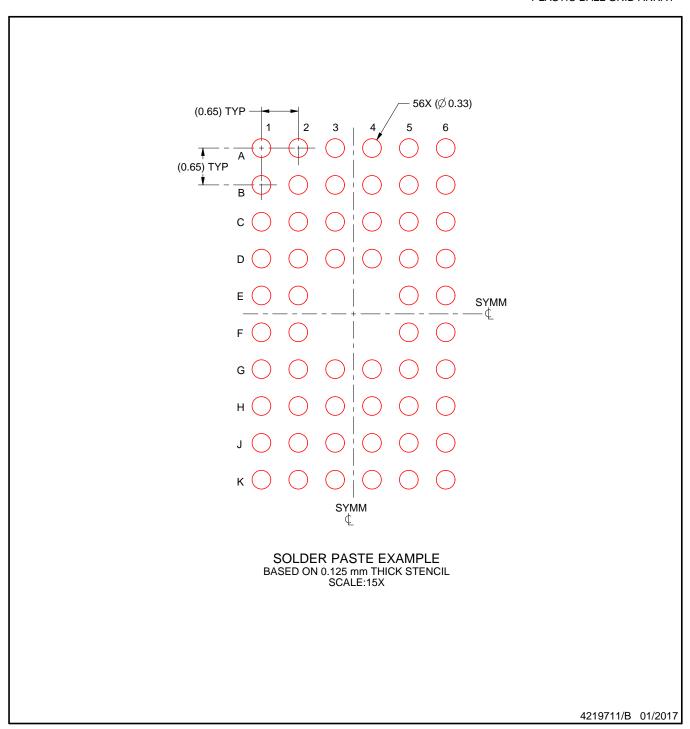


NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For information, see Texas Instruments literature number SPRAA99 (www.ti.com/lit/spraa99).



PLASTIC BALL GRID ARRAY



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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